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## **MPS6507**

# **Amplifier Transistor NPN Silicon**

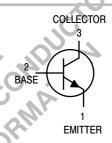
# ON

#### ON Semiconductor®

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TO-92 (TO-226AA) CASE 29-04 STYLE 1



#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector - Emitter Voltage	V <sub>CEO</sub>	20	Vdc
Collector - Base Voltage	V <sub>CBO</sub>	30	Vdc
Emitter - Base Voltage	V <sub>EBO</sub>	3.0	Vdc
Collector Current — Continuous	I <sub>C</sub>	50	mAdc
Total Device Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	625 5.0	mW mW/°C
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	1.5 12	W mW/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}^{(1)}$	200	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	°C/W

#### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

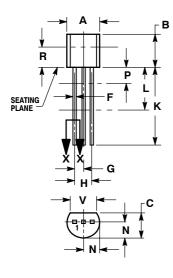
Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage $^{(2)}$ ( $I_C = 1.0 \text{ mAdc}, I_B = 0$ )	V <sub>(BR)CEO</sub>	20	_	_	Vdc
Collector – Base Breakdown Voltage (I <sub>C</sub> = 100 μAdc, I <sub>E</sub> = 0)	V <sub>(BR)</sub> CBO	30			Vdc
Emitter – Base Breakdown Voltage ( $I_E = 100 \mu Adc, I_C = 0$ )	V <sub>(BR)EBO</sub>	3.0			Vdc
Collector Cutoff Current $(V_{CB} = 15 \text{ Vdc}, I_E = 0)$ $(V_{CB} = 15 \text{ Vdc}, I_E = 0, T_A = 60^{\circ}\text{C})$	I <sub>CBO</sub>		_ _	50 1.0	nAdc μAdc
ON CHARACTERISTICS					
DC Current Gain <sup>(2)</sup> $(I_C = 2.0 \text{ mAdc}, V_{CE} = 10 \text{ Vdc})$	h <sub>FE</sub>	25	75	_	_
SMALL-SIGNAL CHARACTERISTICS					
Current–Gain — Bandwidth Product $(I_C = 10 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 100 \text{ MHz})$	f <sub>T</sub>	700	800	_	MHz
Output Capacitance (V <sub>CB</sub> = 10 Vdc, I <sub>E</sub> = 0, f = 1.0 MHz)	C <sub>obo</sub>	_	1.25	2.5	pF
Small–Signal Current Gain ( $I_C = 2.0 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ , $f = 20 \text{ MHz}$ )	h <sub>fe</sub>	20	_	_	_

- 1.  $R_{\theta JA}$  is measured with the device soldered into a typical printed circuit board.
- 2. Pulse Test: Pulse Width  $\leq$  300  $\mu$ s; Duty Cycle  $\leq$  2.0%.

#### MPS6507

#### PACKAGE DIMENSIONS

**CASE 029-04** (TO-226AA) **ISSUE AD** 





#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
- CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
- DIMENSION F APPLIES BETWEEN P AND L.
  DIMENSION D AND J APPLY BETWEEN L AND K MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.022	0.41	0.55
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
Р		0.100		2.54
R	0.115		2.93	
v	0.135		3.43	

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